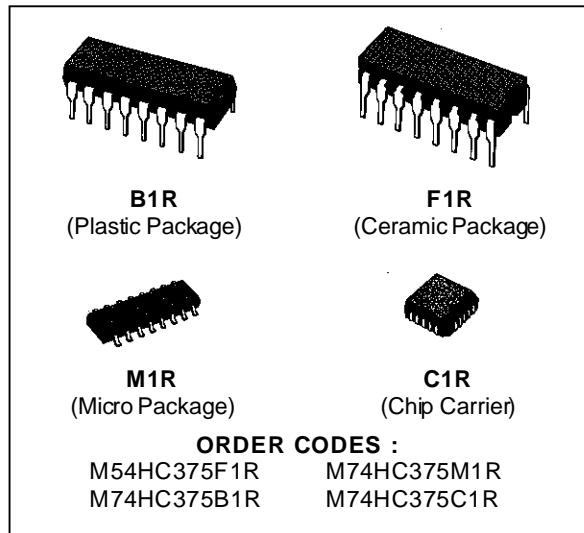


QUAD D TYPE LATCH

- HIGH SPEED
 $t_{PD} = 14 \text{ ns (TYP.) AT } V_{CC} = 5 \text{ V}$
- LOW POWER DISSIPATION
 $I_{CC} = 1 \mu\text{A (MAX.) AT } T_A = 25^\circ\text{C}$
- HIGH NOISE IMMUNITY
 $V_{NIH} = V_{NIL} = 28 \% V_{CC} (\text{MIN.})$
- OUTPUT DRIVE CAPABILITY
 10 LSTTL LOADS
- SYMMETRICAL OUTPUT IMPEDANCE
 $|I_{OH}| = I_{OL} = 4 \text{ mA (MIN.)}$
- BALANCED PROPAGATION DELAYS
 $t_{PLH} = t_{PHL}$
- WIDE OPERATING VOLTAGE RANGE
 $V_{CC} (\text{OPR}) = 2 \text{ V TO } 6 \text{ V}$
- PIN AND FUNCTION COMPATIBLE WITH
 54/74LS375



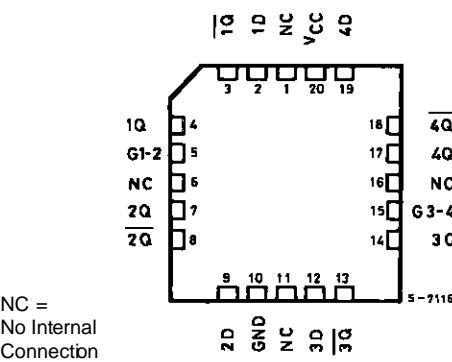
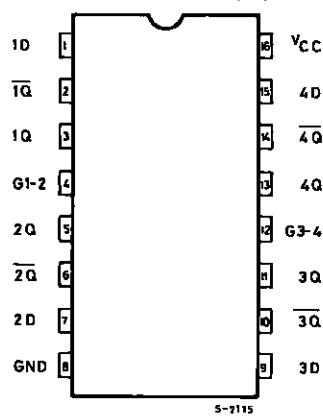
DESCRIPTION

The M54/74HC375 is a high speed CMOS QUAD D TYPE LATCH fabricated in silicon gate C²MOS technology. It has the same high speed performance of LSTTL combined with true CMOS low power consumption. It contains two groups of 2-bit latches controlled by an enable input (G1 . 2 or G3 . 4).

These two latch groups can be used in the different circuits. Each latch has Q and \bar{Q} outputs (1Q to 4Q and 1Q to 4Q). The data applied to the data input is transferred to the Q and \bar{Q} outputs when the enable input is taken high and the outputs will follow the data input as long as the enable input is kept high. When the enable input is taken low, the information data applied to the data input at that time is retained at the outputs.

All inputs are equipped with protection circuits against static discharge and transient excess voltage.

PIN CONNECTIONS (top view)



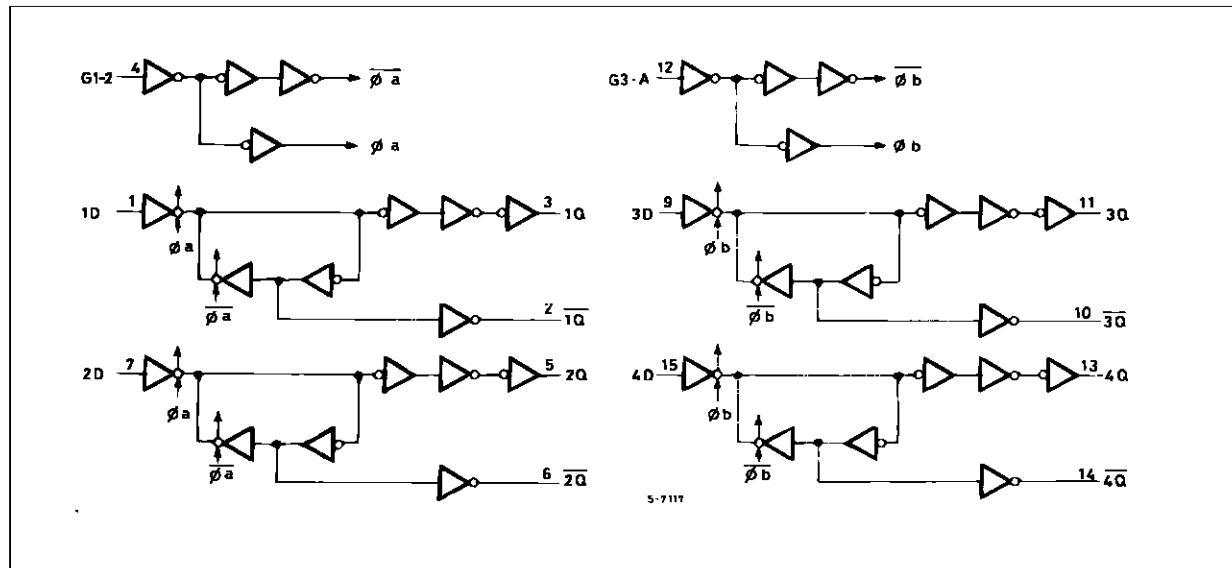
M54/M74HC375

TRUTH TABLE

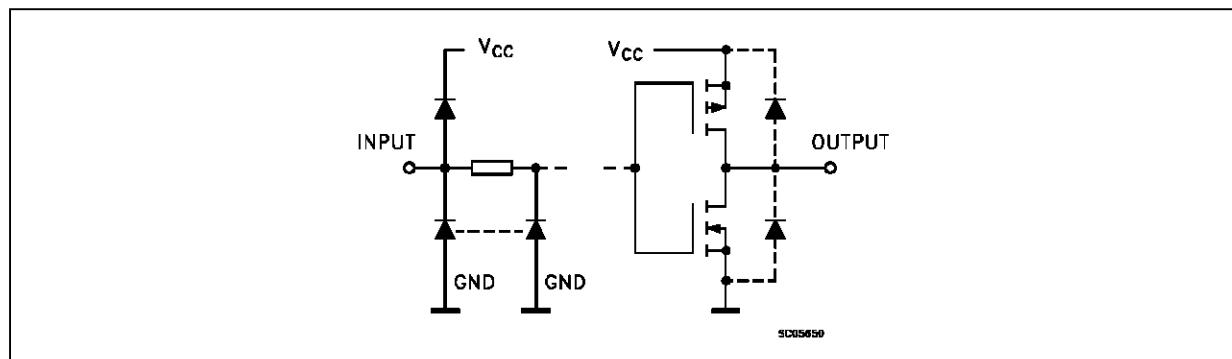
INPUTS		OUTPUTS		FUNCTION
D	G	Q	\bar{Q}	
L	H	L	H	
H	H	H	L	
X	L	Q_n	\bar{Q}_n	LATCH

X: DON'T CARE

LOGIC DIAGRAM

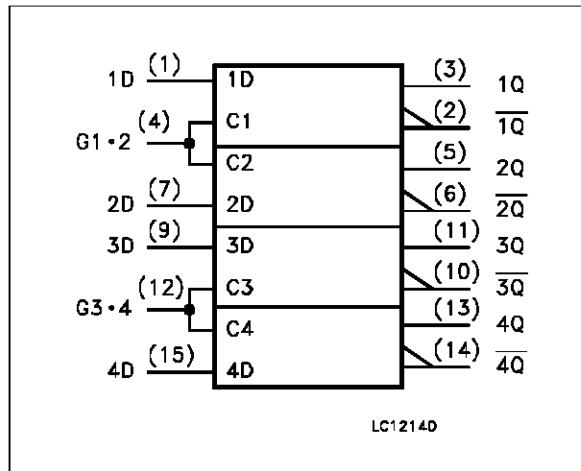


INPUT AND OUTPUT EQUIVALENT CIRCUIT



PIN DESCRIPTION

PIN No	SYMBOL	NAME AND FUNCTION
1, 7, 9, 15	1D to 4D	Data Inputs
3, 5, 11, 13, 2, 6, 10, 14	1Q to 4Q 1Q to 4Q	Outputs
4	G1- 2	Enable Input
12	G3 - 4	Enable Input
8	GND	Ground (0V)
16	V _{CC}	Positive Supply Voltage

IEC LOGIC SYMBOL**ABSOLUTE MAXIMUM RATINGS**

Symbol	Parameter	Value	Unit
V _{CC}	Supply Voltage	-0.5 to +7	V
V _I	DC Input Voltage	-0.5 to V _{CC} + 0.5	V
V _O	DC Output Voltage	-0.5 to V _{CC} + 0.5	V
I _{IK}	DC Input Diode Current	± 20	mA
I _{OK}	DC Output Diode Current	± 20	mA
I _O	DC Output Source Sink Current Per Output Pin	± 25	mA
I _{CC} or I _{GND}	DC V _{CC} or Ground Current	± 50	mA
P _D	Power Dissipation	500 (*)	mW
T _{stg}	Storage Temperature	-65 to +150	°C
T _L	Lead Temperature (10 sec)	300	°C

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these condition is not implied.

(*) 500 mW: \equiv 65 °C derate to 300 mW by 10mW/°C: 65 °C to 85 °C

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Value	Unit
V _{CC}	Supply Voltage	2 to 6	V
V _I	Input Voltage	0 to V _{CC}	V
V _O	Output Voltage	0 to V _{CC}	V
T _{op}	Operating Temperature: M54HC Series M74HC Series	-55 to +125 -40 to +85	°C °C
t _r , t _f	Input Rise and Fall Time	V _{CC} = 2 V	0 to 1000
		V _{CC} = 4.5 V	0 to 500
		V _{CC} = 6 V	0 to 400

M54/M74HC375

DC SPECIFICATIONS

Symbol	Parameter	Test Conditions		Value						Unit	
		V _{cc} (V)		T _A = 25 °C 54HC and 74HC			-40 to 85 °C 74HC		-55 to 125 °C 54HC		
				Min.	Typ.	Max.	Min.	Max.	Min.	Max.	
V _{IH}	High Level Input Voltage	2.0 4.5 6.0		1.5			1.5		1.5		V
				3.15			3.15		3.15		
				4.2			4.2		4.2		
V _{IL}	Low Level Input Voltage	2.0 4.5 6.0				0.5		0.5		0.5	V
						1.35		1.35		1.35	
						1.8		1.8		1.8	
V _{OH}	High Level Output Voltage	2.0 4.5 6.0 4.5 6.0	V _I = V _{IH} or V _{IL}	I _O =-20 μA	1.9	2.0		1.9		1.9	V
					4.4	4.5		4.4		4.4	
					5.9	6.0		5.9		5.9	
				I _O =-4.0 mA	4.18	4.31		4.13		4.10	
					5.68	5.8		5.63		5.60	
V _{OL}	Low Level Output Voltage	2.0 4.5 6.0 4.5 6.0	V _I = V _{IH} or V _{IL}	I _O = 20 μA		0.0	0.1		0.1	0.1	V
						0.0	0.1		0.1	0.1	
						0.0	0.1		0.1	0.1	
				I _O = 4.0 mA		0.17	0.26		0.33	0.40	
						0.18	0.26		0.33	0.40	
I _I	Input Leakage Current	6.0	V _I = V _{cc} or GND			±0.1		±1		±1	μA
I _{CC}	Quiescent Supply Current	6.0	V _I = V _{cc} or GND			2		20		40	μA

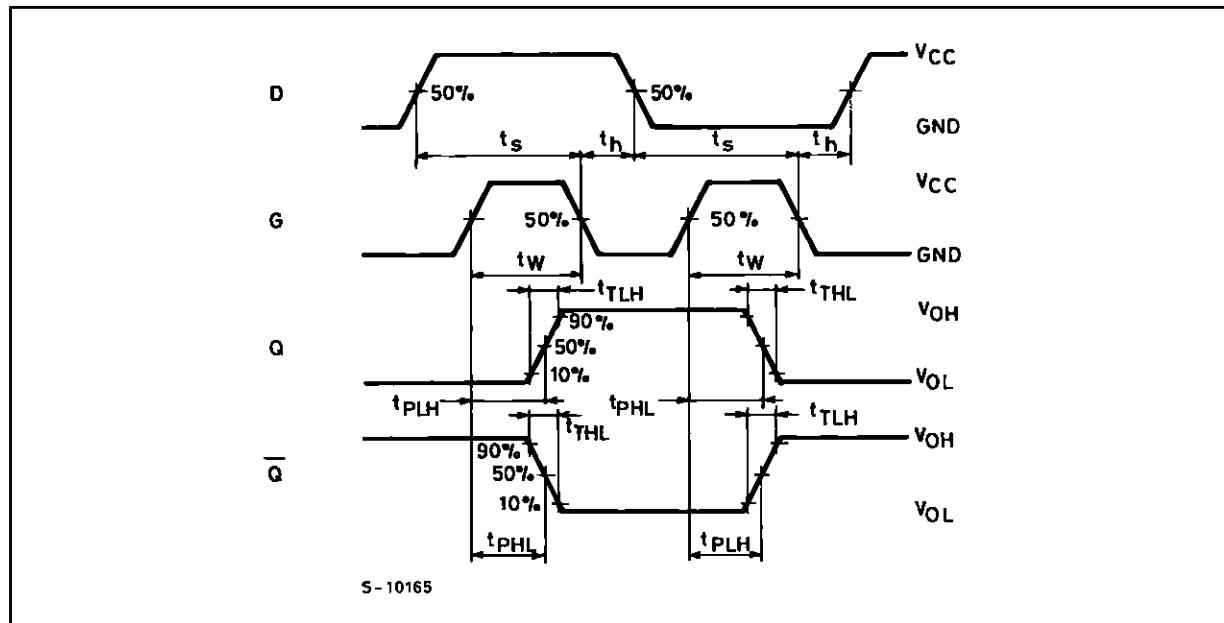
AC ELECTRICAL CHARACTERISTICS ($C_L = 50 \text{ pF}$, Input $t_r = t_f = 6 \text{ ns}$)

Symbol	Parameter	Test Conditions		Value						Unit	
		V _{CC} (V)		T _A = 25 °C 54HC and 74HC			-40 to 85 °C 74HC		-55 to 125 °C 54HC		
				Min.	Typ.	Max.	Min.	Max.	Min.	Max.	
t _{TLH} t _{THL}	Output Transition Time	2.0			30	75		95		110	ns
		4.5			8	15		19		22	
		6.0			7	13		16		19	
t _{PLH} t _{PHL}	Propagation Delay Time (DATA - Q, \bar{Q})	2.0			56	115		145		175	ns
		4.5			14	23		29		35	
		6.0			12	20		25		30	
t _{PLH} t _{PHL}	Propagation Delay Time (G - Q, \bar{Q})	2.0			52	105		130		160	ns
		4.5			13	21		26		32	
		6.0			11	18		22		27	
t _{(V)H}	Minimum Enable Pulse Width (G)	2.0			12	75		95		115	ns
		4.5			3	15		19		23	
		6.0			3	13		16		20	
t _S	Minimum Set-up Time (DATA - G)	2.0			20	75		95		115	ns
		4.5			5	15		19		23	
		6.0			4	13		16		20	
t _H	Minimum Hold Time (DATA - G)	2.0			0		0		0	0	ns
		4.5			0		0		0	0	
		6.0			0		0		0	0	
C _{IN}	Input Capacitance				5	10		10		10	pF
C _{PD} (*)	Power Dissipation Capacitance				52						pF

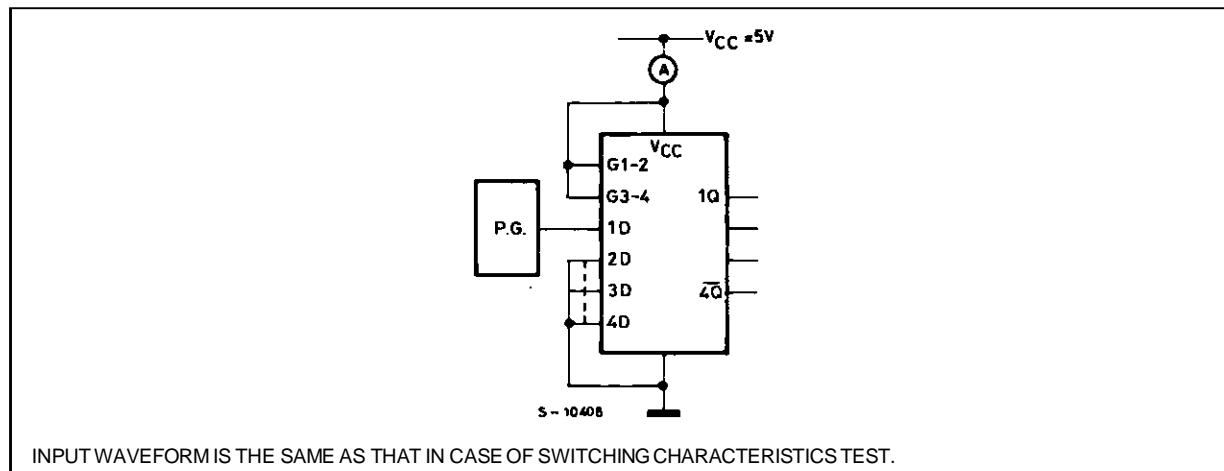
(*) C_{PD} is defined as the value of the IC's internal equivalent capacitance which is calculated from the operating current consumption without load. (Refer to Test Circuit). Average operating current can be obtained by the following equation. I_{CC(Opr)} = C_{PD} • V_{CC} • f_{IN} + I_{CC}

M54/M74HC375

SWITCHING CHARACTERISTICS TEST WAVEFORM

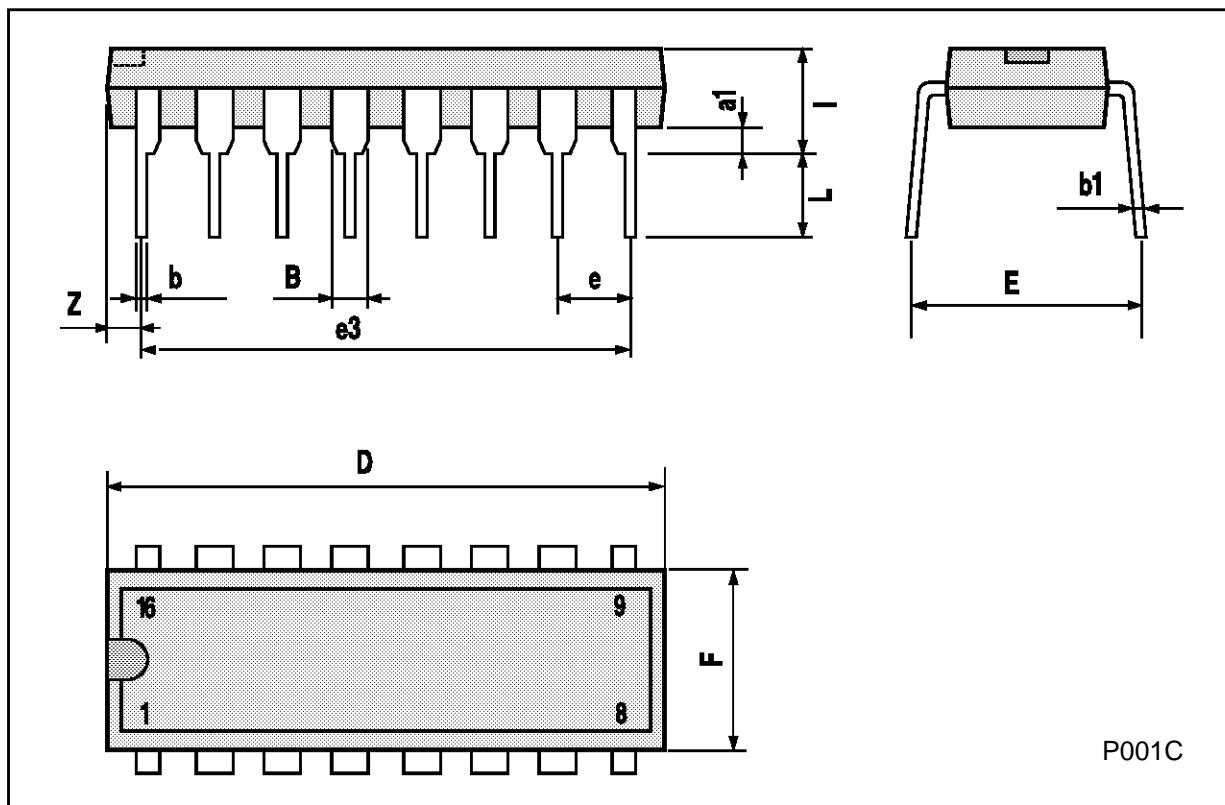


TEST CIRCUIT I_{cc} (Opr.)



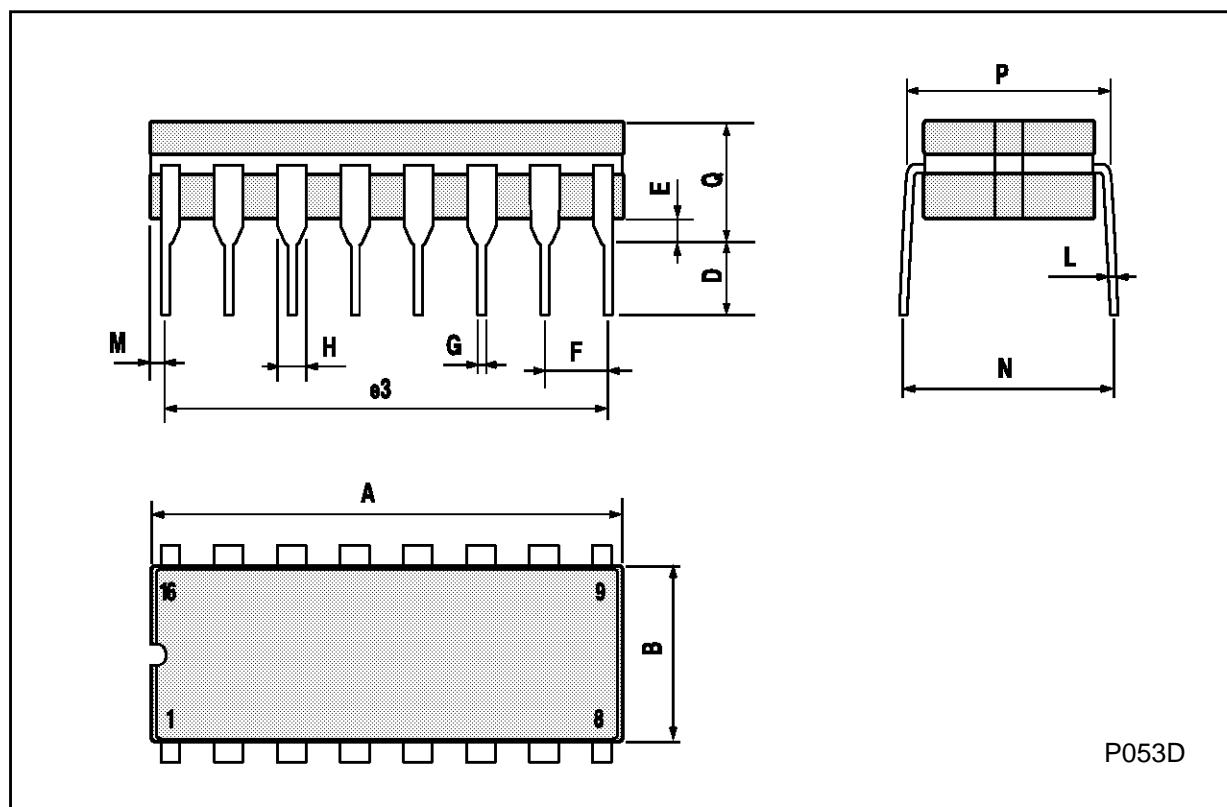
Plastic DIP16 (0.25) MECHANICAL DATA

DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
a1	0.51			0.020		
B	0.77		1.65	0.030		0.065
b		0.5			0.020	
b1		0.25			0.010	
D			20			0.787
E		8.5			0.335	
e		2.54			0.100	
e3		17.78			0.700	
F			7.1			0.280
I			5.1			0.201
L		3.3			0.130	
Z			1.27			0.050



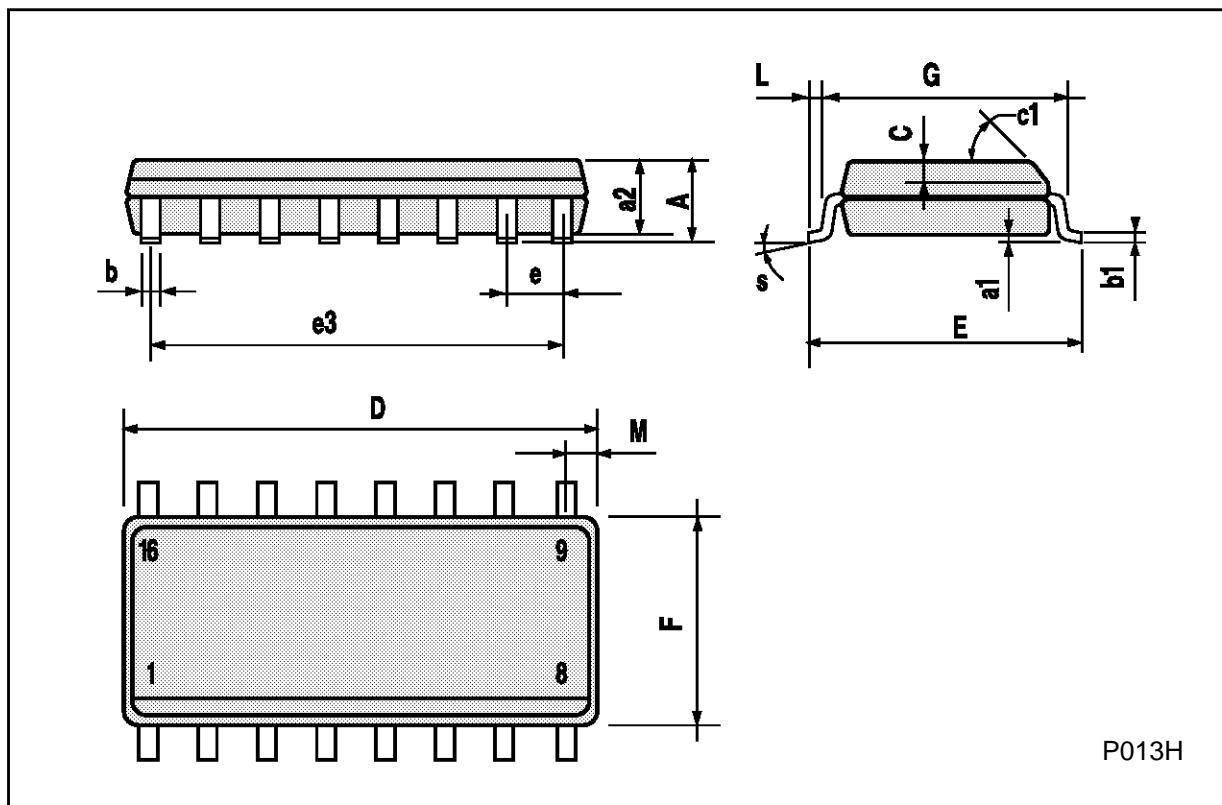
Ceramic DIP16/1 MECHANICAL DATA

DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A			20			0.787
B			7			0.276
D		3.3			0.130	
E	0.38			0.015		
e3		17.78			0.700	
F	2.29		2.79	0.090		0.110
G	0.4		0.55	0.016		0.022
H	1.17		1.52	0.046		0.060
L	0.22		0.31	0.009		0.012
M	0.51		1.27	0.020		0.050
N			10.3			0.406
P	7.8		8.05	0.307		0.317
Q			5.08			0.200



SO16 (Narrow) MECHANICAL DATA

DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A			1.75			0.068
a1	0.1		0.2	0.004		0.007
a2			1.65			0.064
b	0.35		0.46	0.013		0.018
b1	0.19		0.25	0.007		0.010
C		0.5			0.019	
c1			45° (typ.)			
D	9.8		10	0.385		0.393
E	5.8		6.2	0.228		0.244
e		1.27			0.050	
e3		8.89			0.350	
F	3.8		4.0	0.149		0.157
G	4.6		5.3	0.181		0.208
L	0.5		1.27	0.019		0.050
M			0.62			0.024
S			8° (max.)			



P013H

PLCC20 MECHANICAL DATA

DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A	9.78		10.03	0.385		0.395
B	8.89		9.04	0.350		0.356
D	4.2		4.57	0.165		0.180
d1		2.54			0.100	
d2		0.56			0.022	
E	7.37		8.38	0.290		0.330
e		1.27			0.050	
e3		5.08			0.200	
F		0.38			0.015	
G			0.101			0.004
M		1.27			0.050	
M1		1.14			0.045	



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